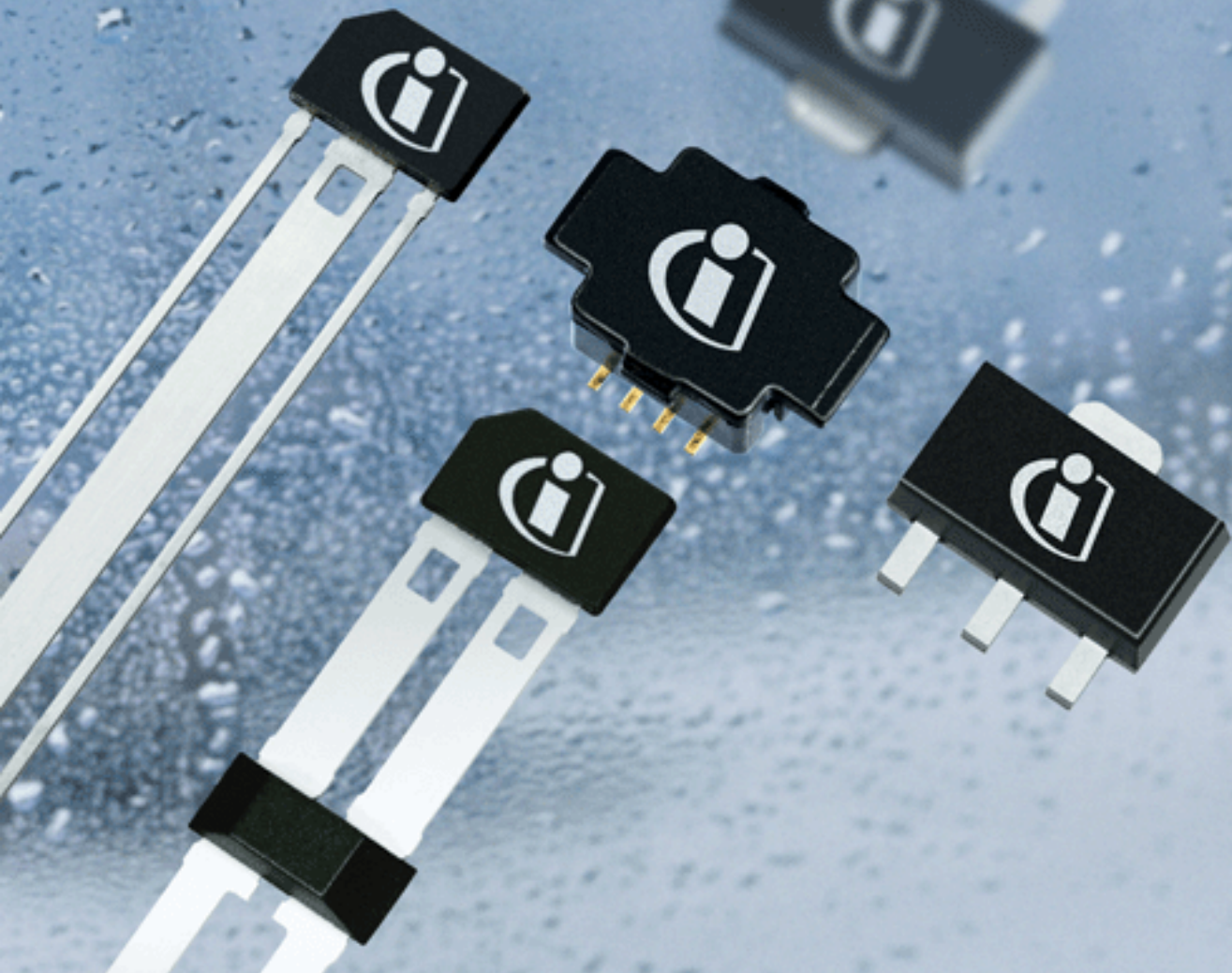


# TLE4953 TLE4953C

Differential Two-Wire Hall Effect Sensor IC



Sensors



Never stop thinking

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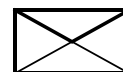
**TLE4953**  
**TLE4953C****Revision History:        2010-04****V 4.0**

Previous Version:        V 3.0

Page	Temperature profile adjustment
	TLE4953C package change
	Maximum value of the differential direction limit added
	Storage temperature info provided by application notes: Storage of products supply by Infineon Technologies

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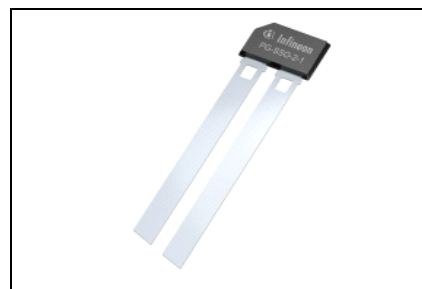
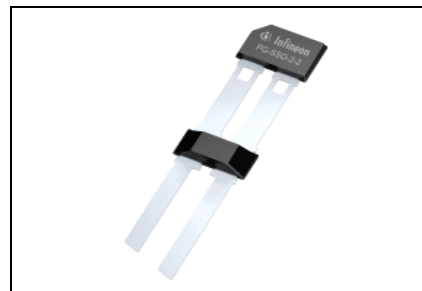
## Differential Two-Wire Hall Effect Sensor IC

**TLE4953**  
**TLE4953C**

### Data Sheet V4.0

#### Features

- Two-wire PWM current interface
- Detection of rotation direction
- Dynamic self-calibration principle & high sensitivity
- Adaptive hysteresis
- Single chip solution - no external components
- Vibration suppression in calibrated mode
- South and north pole pre-induction possible
- High resistance to piezo effects
- Large operating air-gaps
- Wide operating temperature range
- From zero speed up to 12 kHz
- 1.8 nF overmolded capacitor
- For coarse transmission target wheels

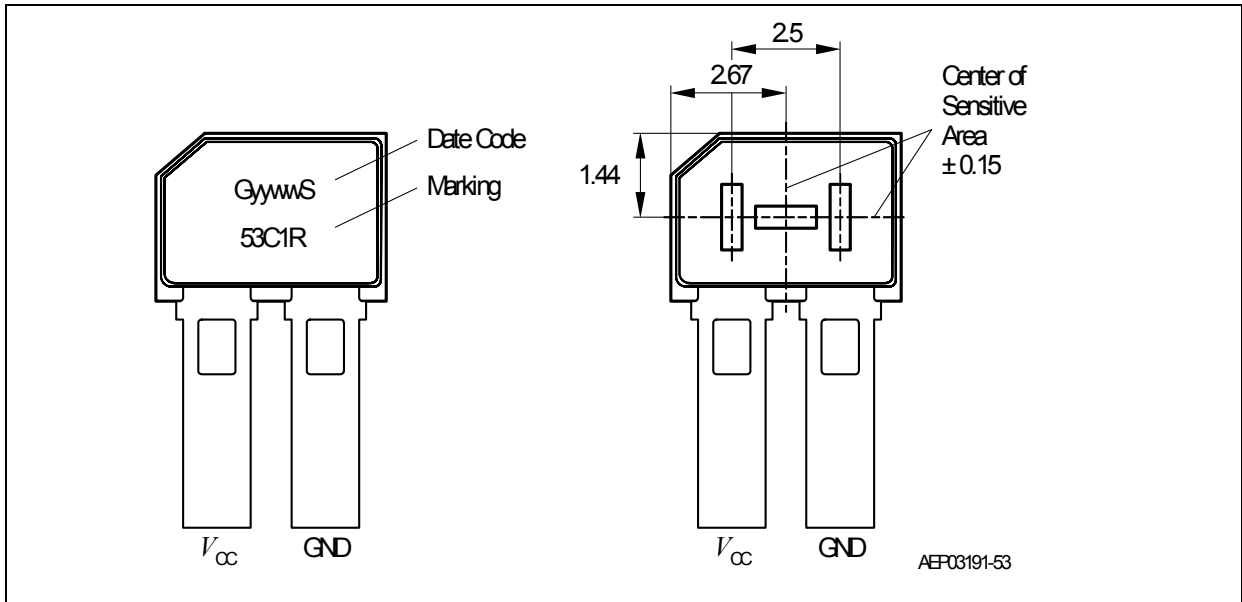


Type	Marking	Order Code	Package
TLE4953C	53C1R	SP000710696	PG-SSO-2-4
TLE4953	53	SP000278512	PG-SSO-2-1

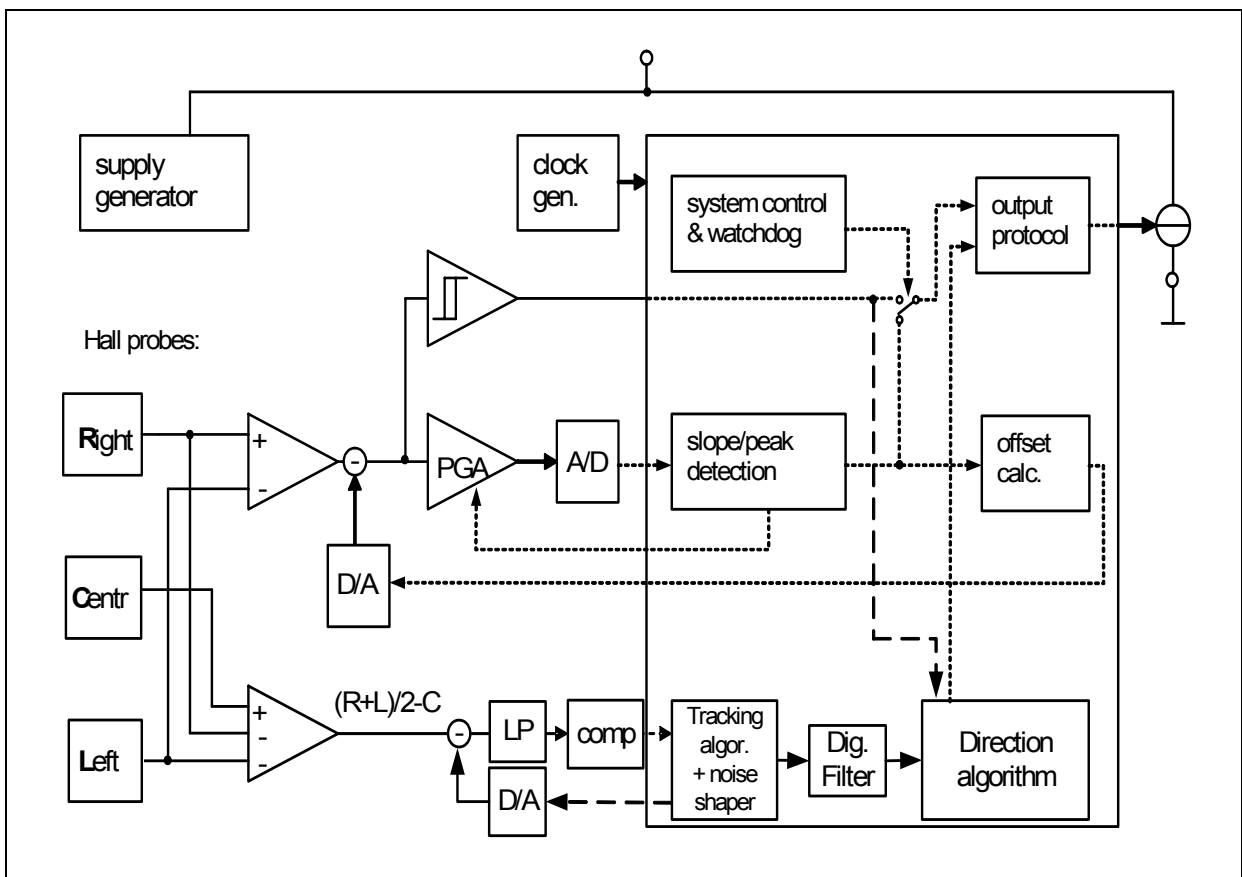
The differential Hall Effect sensor TLE4953 is designed to provide information about rotational speed and direction of rotation to modern transmission and ABS systems. The output has been designed as a two wire current interface based on a Pulse Width Modulation principle. The sensor operates without external components and combines a fast power-up time with a wide frequency range. Excellent accuracy and sensitivity is specified for harsh automotive requirements as a wide temperature range, high ESD robustness and high EMC resilience. State-of-the-art BiCMOS technology is used for monolithic integration of the active sensor areas and the signal conditioning.

Finally, the optimized piezo compensation and the integrated dynamic offset compensation enable easy manufacturing and elimination of magnetic offsets. Adaptive hysteresis concept increases the noise immunity. The TLE4953C is additionally provided with an overmolded 1.8 nF capacitor for improved EMI performance.

## Pin Configuration (top view)



**Figure 1**



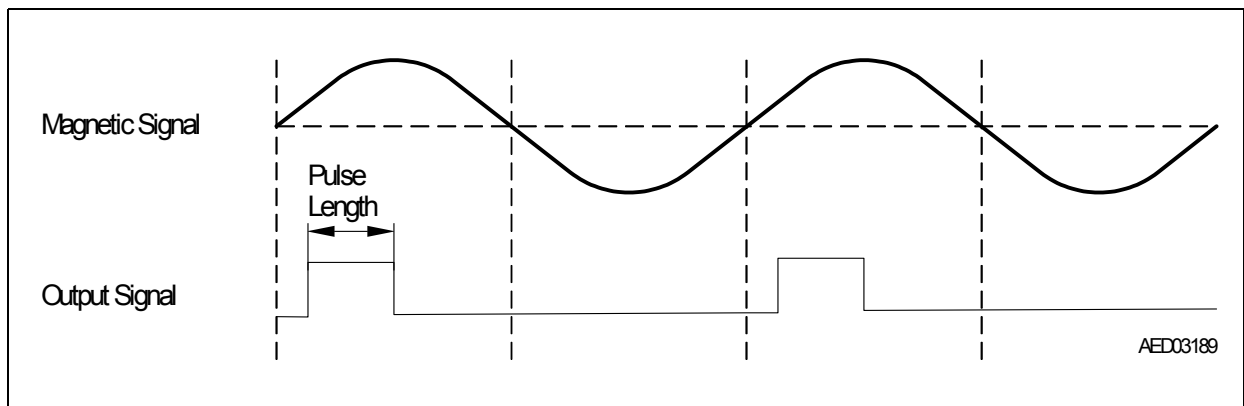
**Figure 2 Block Diagram**

## Functional Description

The differential Hall Effect IC detects the motion of ferromagnetic or permanent magnet structures by measuring the differential flux density of the magnetic field. To detect the motion of ferromagnetic objects the magnetic field must be provided by a backbiasing permanent magnet. Either the South or North pole of the magnet can be attached to the rear, unmarked side (remark: rear side may contain data matrix code) of the IC package.

Magnetic offsets of up to  $\pm 20$  mT and mechanical offsets are cancelled out through a self-calibration algorithm. Only 2 transitions are necessary for the self-calibration procedure. After the initial self-calibration sequence switching occurs when the input signal crosses the adaptive threshold on the rising magnetic edge.

The ON and OFF state of the IC are indicated by **High** and **Low** current consumption. Each rising magnetic edge of the magnetic input signal triggers an output pulse.



**Figure 3 Output Pulses on magnetic rising edge**

In addition to the speed signal, the following information is provided by varying the length of the output pulses (PWM modulation):

**Speed signal = S**

The speed signal is issued at the first output pulse after start up and when the magnetic frequency is above 1kHz.

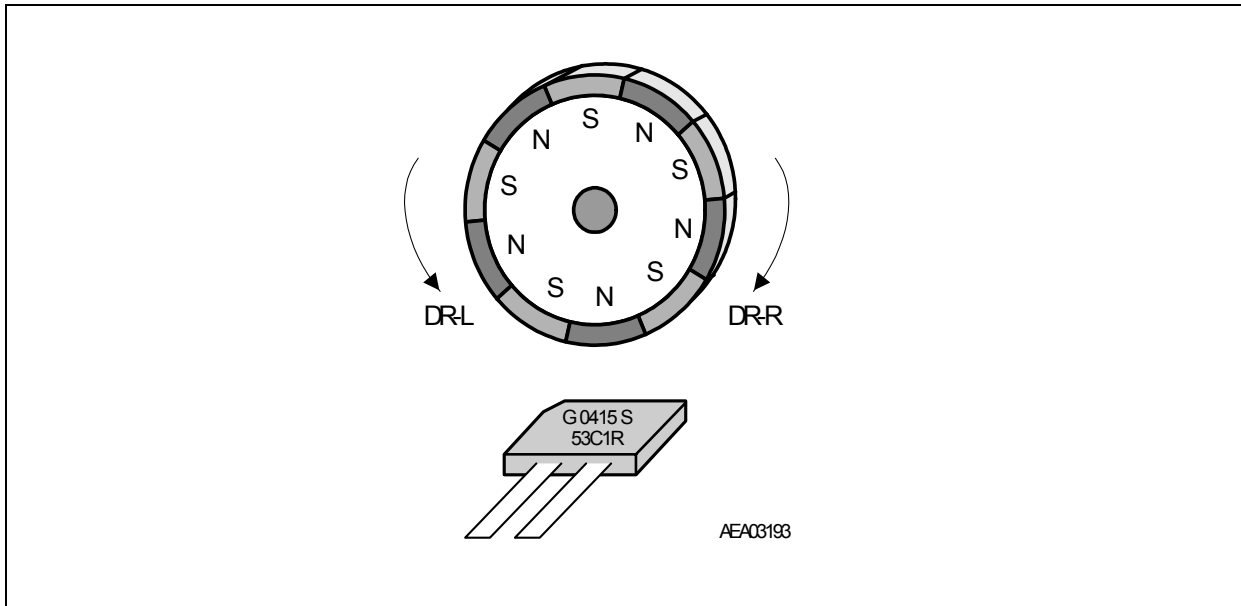
**Direction of rotation left = DR-L**

DR-L information is issued in the output pulse length when the active target wheel in front of the Hall Effect IC moves from the pin  $V_{CC}$  to the pin GND.

**Direction of rotation right = DR-R**

DR-R information is issued in the output pulse length when the active target wheel in front of the Hall Effect IC moves from the pin GND to the pin  $V_{CC}$ .





**Figure 4 Definition of Rotation Direction**

### Circuit Description

The circuit internally is supplied by a voltage regulator. A 2 MHz on-chip oscillator serves as a clock generator for the DSP and the output encoder.

### Speed signal circuitry

TLE4953 speed signal path comprises a pair of Hall Effect probes, separated from each other by 2.5 mm, a differential amplifier including noise limiting low-pass filter, and a comparator triggering a switched current output stage. An offset cancellation feedback loop is provided through a signal-tracking A/D converter, a digital signal processor (DSP), and an offset cancellation D/A converter.

### Uncalibrated Mode

Occasionally a short initial offset settling time  $t_{d,input}$  might delay the detection of the input signal. (The sensor is "blind"). During the startup phase (un-calibrated mode) the output is disabled ( $I = I_{Low}$ ). The magnetic input signal is tracked by the speed ADC and monitored within the digital circuit. For detection the signal needs to exceed a threshold (digital noise constant d1). When the signal slope is identified as a rising edge, a trigger pulse is issued to a comparator. A second trigger pulse is issued as soon as the next rising edge is detected.

Between the start-up of the magnetic input signal and the time when its second extreme is reached, the PGA (programmable gain amplifier) will switch to its appropriate position. This value is determined by the signal amplitude and initial offset value. The digital noise constant value is changing accordingly ( $d1 \rightarrow d2$ , related to the corresponding PGA

states), leading to a change in phase shift between magnetic input signal and output signal. After that consecutive output edges should have a nominal delay of about  $360^\circ$ . During the uncalibrated mode the offset value is calculated by the peak detection algorithm as described below.

The differential input signal is digitized in the speed A/D converter and fed into the DSP part of the circuit. The minimum and maximum values of the input signal are extracted and their corresponding arithmetic mean value is calculated. The offset of this mean value is determined and fed into the offset cancellation DAC.

The offset update takes place when two valid extremes are found and the direction of the update has the same orientation as the magnetic slope (valid for calibrated mode). For example an positive offset update is only possible on a rising magnetic edge. The offset update is done independant from the output switching.

After successful correction of the offset, the output switching is in calibrated mode. Switching occurs at adaptive threshold-crossover. It is only affected by the propagation delay time of the signal path, which is mainly determined by the noise limiting filter. Signals which are below a predefined threshold  $\Delta B_{\text{Limit}}$  are not detected. This prevents unwanted switching.

The adaptive hysteresis is linked to the PGA state. Therefore the system is able to suppress switching if vibration or noise signals are smaller than the adaptive hysteresis.

The switching and direction information is fed into the DSP and the output encoder. The pulse length of the **High** output current is generated according to the rotational speed and the direction of rotation.

### Direction signal circuitry

The differential signal between a third Hall probe and the mean value of the differential Hall probe pair is obtained from the direction input amplifier. This signal is digitized by the direction ADC and fed into the digital circuitry. There, the phase of the signal referring to the speed signal is analyzed and the direction information is forwarded to the output encoder. The phase is identified by calculating the size of the direction signal at two consecutive zero crossings of the speed signal. This is done by subtracting the current direction signal from the internal stored value which has been taken from the previous magnetic edge.

Depending on the phase shift between the direction signal and the speed signal a positive or a negative value occur. The information if the new direction calculation takes place at a rising or a falling magnetic edge allows together with the algebraic sign of the calculated direction signal a reliable direction detection.

The first pulse after power is always a speed pulse as there is no stored direction information available.



**Vibration suppression algorithm:**

The magnetic signal amplitude and the direction information is used for detection of parasitic magnetic signals. Unwanted magnetic signals can be caused by angular or airgap vibrations for instance. If an input signal is clearly detected as a vibration signal, the output of pulses will be suppressed.

A magnetic input signal is classified as parasitic vibration signal if

- a. the speed signal amplitude is smaller than the internal hysteresis or
- b. the direction signal amplitude is smaller than the internal limit or
- c. the direction signal consists of alternating left/right information

The quality of vibration suppression (according a & b) depends on the hysteresis limits and on the magnitude of the magnetic signal. The bigger the hysteresis the better the suppression of parasitic signals.

For parasitic signals where items above (a. to c.) are not clearly applicable or at other more rare cases (e.g. IC startup) vibration suppression is not guaranteed. The performance of the direction detection and vibration suppression algorithm depends on the used magnetic circuit and as well on the used target wheel and need to be evaluated.

Please ask for application support if you have questions on the vibration suppression algorithm.

**Package information:**

Pure tin covering (green lead plating) is used. Lead frame material is Wieland K62 (UNS: C18090) and contains CuSn1CrNiTi. Product is RoHS (**R**estriction **o**f **H**azardous **S**ubstances) compliant and marked with letter G in front of the data code marking and may contain a data matrix code on the rear side of the package (see also information note 136/03). Please refer to your key account team or regional sales if you need further information.

**Absolute Maximum Ratings**
 $T_j = -40 \text{ to } 150 \text{ }^{\circ}\text{C}$ ,  $4.0\text{V} \leq V_{CC} \leq 16.5 \text{ V}$ 

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
Supply voltage	$V_{CC}$	- 0.3	–	V	$T_j \leq 80 \text{ }^{\circ}\text{C}$
		–	16.5		$T_j = 170 \text{ }^{\circ}\text{C}$
		–	20		$T_j = 150 \text{ }^{\circ}\text{C}$
		–	22		$t = 10 \times 5 \text{ min}$
		–	24		$t = 10 \times 5 \text{ min}$ , $R_M \geq 75 \text{ } \Omega$ included in $V_{CC}$
		–	27		$t = 400 \text{ ms}$ , $R_M \geq 75 \text{ } \Omega$ included in $V_{CC}$
Reverse polarity current	$I_{rev}$	–	200	mA	External current limitation required, $t \leq 4 \text{ h}^1)$
Junction temperature	$T_j$	–	150	$^{\circ}\text{C}$	5000 h, $V_{CC} \leq 16.5 \text{ V}$
		–	160		2500 h, $V_{CC} \leq 16.5 \text{ V}$ (not additive)
		–	170		500 h, $V_{CC} \leq 16.5 \text{ V}$ (not additive)
		–	190		$4 \times 1 \text{ h}$ , $V_{CC} \leq 16.5 \text{ V}$
Active lifetime <sup>2)</sup>	$t_{B,active}$	–	10000	h	$-40^{\circ}\text{C}$ to $125^{\circ}\text{C}$
Thermal resistance PG-SSO-2-4, PG-SSO-2-1	$R_{thJA}$	–	190	K/W	<sup>3)</sup>

1) This allows together with an external serial resistor (75 or 100 Ohm) reverse polarity voltage for a short duration. This resistor is usually present in the ECU of the application circuit.

2) Life time shall be considered as anticipation and will not extend the agreed warranty period

3) Can be improved significantly by further processing like overmolding

**Note:** Stress in excess of those listed here may cause permanent damage to the device.  
Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ESD Protection

Characterized according to Human Body Model (HBM) tests in compliance with Standard EIA/JESD22-A114-B HBM (covers MIL STD 883D) )

Parameter	Symbol	Limit Values		Unit	Notes
		min.	max.		
ESD-Protection TLE4953C TLE4953	$V_{\text{ESD}}$	- -	$\pm 12$ $\pm 12$	kV	$R = 1.5 \text{ k}\Omega$ , $C = 100 \text{ pF}$

## Operating Range

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
Supply voltage	$V_{\text{CC}}$	4.5	20	V	Directly on IC leads excludes the $R_{\text{M}}$ voltage drop
Supply voltage	$V_{\text{CC}}$	4.0	4.5	V	Directly on IC leads excludes the $R_{\text{M}}$ voltage drop <sup>1)</sup>
Supply voltage ripple	$V_{\text{AC}}$	–	6	Vpp	$V_{\text{CC}} = 13 \text{ V}$ $0 \leq f \leq 50 \text{ kHz}$
Junction temperature	$T_{\text{j}}$	– 40	150	°C	
	or		170		500h $V_{\text{CC}} \leq 16.5 \text{ V}$ <sup>2)</sup>
Pre-induction	$B_0$	– 500	+ 500	mT	
Pre-induction offset between outer probes	$\Delta B_{\text{stat., l/r}}$	– 20	+ 20	mT	L-R
Pre-induction offset between mean of outer probes and center probe	$\Delta B_{\text{stat., m/o}}$	– 20	+ 20	mT	(L+R)/2-C
Differential Induction	$\Delta B$	– 120	+ 120	mT	

- 1) Reduced performance possible for jitter/phase accuracy and power supply rejection ratio (EMC). Current levels will typically decrease but will be within specification limits. This voltage range is not recommended for continuous operation and should cover the function during short voltage drops which may occur at cranking of engine / test pulse 4.
- 2) increased jitter and reduced phase accuracy permissible between 150 and 170°C junction temperature.

*Note: Within the operating range the functions given in the circuit description are fulfilled.*

### AC/DC Characteristics

All values specified at constant amplitude and offset of input signal, over operating range, unless otherwise specified. Typical values correspond to  $V_{CC}=12V$  and  $T_A=25^\circ C$

Parameter	Symbol	Limit Values			Unit	Remarks
		min.	typ.	max.		
Supply current	$I_{Low}$	5.9	7	8.4	mA	
Supply current	$I_{High}$	11.8	14	16.8	mA	
Supply current ratio	$I_{High}/I_{Low}$	1.9	–	–		
Output rise/fall slew rate TLE4953	$t_r, t_f$	12	–	26	mA/ $\mu s$	$R_M = 75 \Omega$ $T_j \leq 170^\circ C$ See <b>Figure 5</b>
Output rise/fall slew rate TLE4953C	$t_r, t_f$	8	–	26	mA/ $\mu s$	$R_M = 75 \Omega$ $T_j \leq 170^\circ C$ See <b>Figure 5</b>
Current ripple $dI_X/dV_{CC}$	$I_X$	–	–	90	$\mu A/V$	Only valid for TLE4953
Limit threshold speed $0Hz \leq f \leq 2500 Hz$ $2500 Hz \leq f \leq 12000 Hz$	$\Delta B_{Limit}$	0.35	0.8	1.5 1.75	mT	1)
Limit differential direction signal $0Hz \leq f \leq 1100 Hz$	$\Delta B_{Dir}$		0.35	0.73	mT	Calculated at two consecutive threshold crossings <sup>2)</sup>
Initial calibration delay time	$t_{d,input}$	–	300	345	$\mu s$	Additional to $n_{start}$
Magnetic edges required for first output pulse (no previous vibration detected)	$n_{start}$	–	–	2	magn. edges	pulse occurs only on rising magnetic edge
Number of pulses in uncalibrated mode	$n_{DZ-Startup}$			2	pulses	3 <sup>rd</sup> pulse calibrated
Number of emitted pulses with invalid direction information <sup>3)</sup>	$n_{DR-Start}$	–	–	2 <sup>4)</sup>	pulses	3 <sup>rd</sup> pulse correct
Frequency	$f$	0	–	12000	Hz	4)

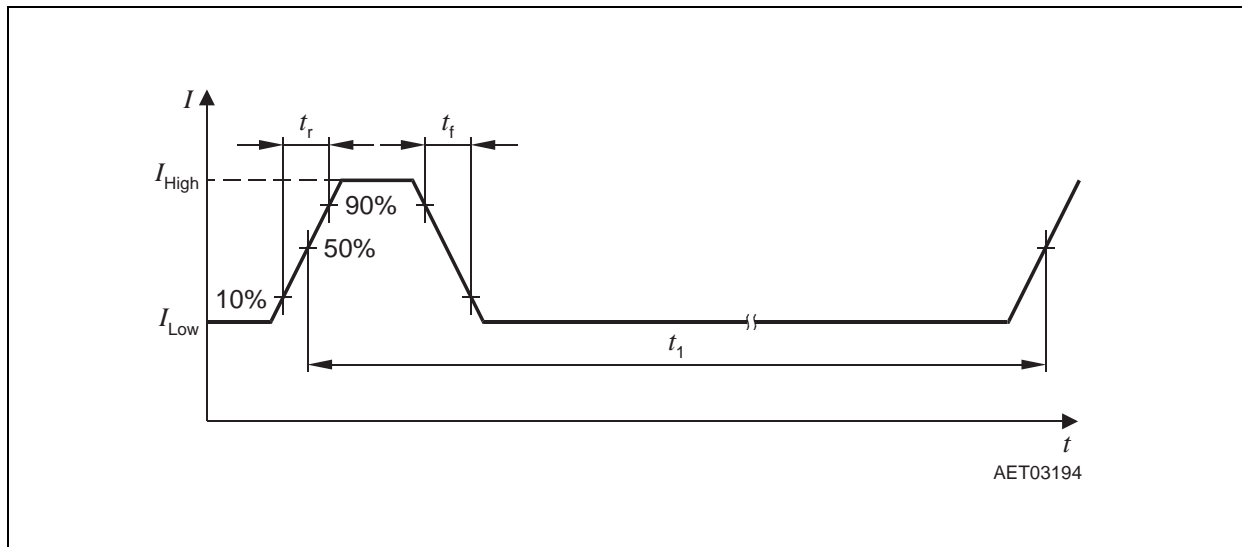
### AC/DC Characteristics (cont'd)

All values specified at constant amplitude and offset of input signal, over operating range, unless otherwise specified. Typical values correspond to  $V_{CC}=12V$  and  $T_A=25^{\circ}C$

Parameter	Symbol	Limit Values			Unit	Remarks
		min.	typ.	max.		
Systematic phase error of output edges during start-up and uncalibrated mode		- 88		+ 88	°	Systematical phase error of "uncal" pulse; nth vs. n+1th pulse (does not include jitter)
Phase shift during transition from uncalibrated to calibrated mode	$\Delta\Phi_{\text{switch}}$	- 90		+ 90	°	
Phase shift change during PGA switching in calibrated mode		0		80	°	Due to adaptive hysteresis. Depending on signal shape.
Magnetic differential field change required for startup with 1st rising edge	$\Delta\hat{B}_{\text{Limit, early startup}}$					peak to peak value
$\Delta\hat{B}_{\text{Limit, early startup}}$				3.5	mT	
Jitter, $T_j \leq 150^{\circ}C$ $T_j \leq 170^{\circ}C$ $f \leq 2500 \text{ Hz}$	$S_{\text{Jit-far}}$	-	-	$\pm 2$ $\pm 3$	%	<sup>5)</sup> 1 $\sigma$ value $V_{CC} = 12 \text{ V}$ $\Delta B \geq 2 \text{ mT}$
Jitter, $T_j \leq 150^{\circ}C$ $T_j \leq 170^{\circ}C$ $2500 \text{ Hz} < f \leq 12000 \text{ Hz}$	$S_{\text{Jit-far}}$	-	-	$\pm 3$ $\pm 4.5$	%	<sup>5)</sup> 1 $\sigma$ value $V_{CC} = 12 \text{ V}$ $\Delta B \geq 2 \text{ mT}$
Jitter at board net ripple	$S_{\text{Jit-AC}}$	-	-	$\pm 2$	%	<sup>5)</sup> $V_{CC} = 13 \text{ V} \pm 6 \text{ Vpp}$ $0 \leq f \leq 50 \text{ kHz}$ $\Delta B = 15 \text{ mT}$

- 1) magnetic amplitude values, sine magnetic field, Limits refer to the 50% criteria. 50% of pulses are missing. Only valid at lowest PGA stage/highest amplification because of adaptive hysteresis.
- 2) Magnetic peak to peak value. Limits refer to the 99% criteria, just 1 pulse missing out of 100.
- 3) The first 2 pulses may contain only direction information if the direction signal is above  $\Delta B_{\text{Dir}}$ . The first pulse after starting will be the speed pulse.
- 4) High frequency behaviour not subject to production test - verified by design/characterization.

5) not subject to production test- verified by design/characterization, magnetic values are amplitude values



**Figure 5** Definition of Rise and Fall Time

### Timing Characteristics

Parameter	Symbol	Limit Values			Unit	Remarks
		min.	typ.	max.		
Pre-low length	$t_{\text{pre-low}}$	24	30	36	$\mu\text{s}$	
Speed signal	$t_{\text{S}}$	24	30	36	$\mu\text{s}$	
Length of DR-L pulse	$t_{\text{DR-L}}$	50	60	70	$\mu\text{s}$	
Length of DR-R pulse	$t_{\text{DR-R}}$	102	120	138	$\mu\text{s}$	
Output of DR-L/R pulse, maximum frequency	$f_{\text{DR, max}}$				Hz	Internal hysteresis of direction signal <sup>1)</sup>
From low - high frequency		935	1100	1265		
From high - low frequency		850	1000	1150		

1) Not possible overlap, 10% difference verified by design/characterization. Frequencies not subject to production test verified by design/characterization

### PWM Current Interface

Between each magnetic transition and the rising edge of the corresponding output pulse the output current is **Low** for  $t_{\text{pre-low}}$  in order to allow reliable internal conveyance. Following the signal pulse (current is **High**) is output.

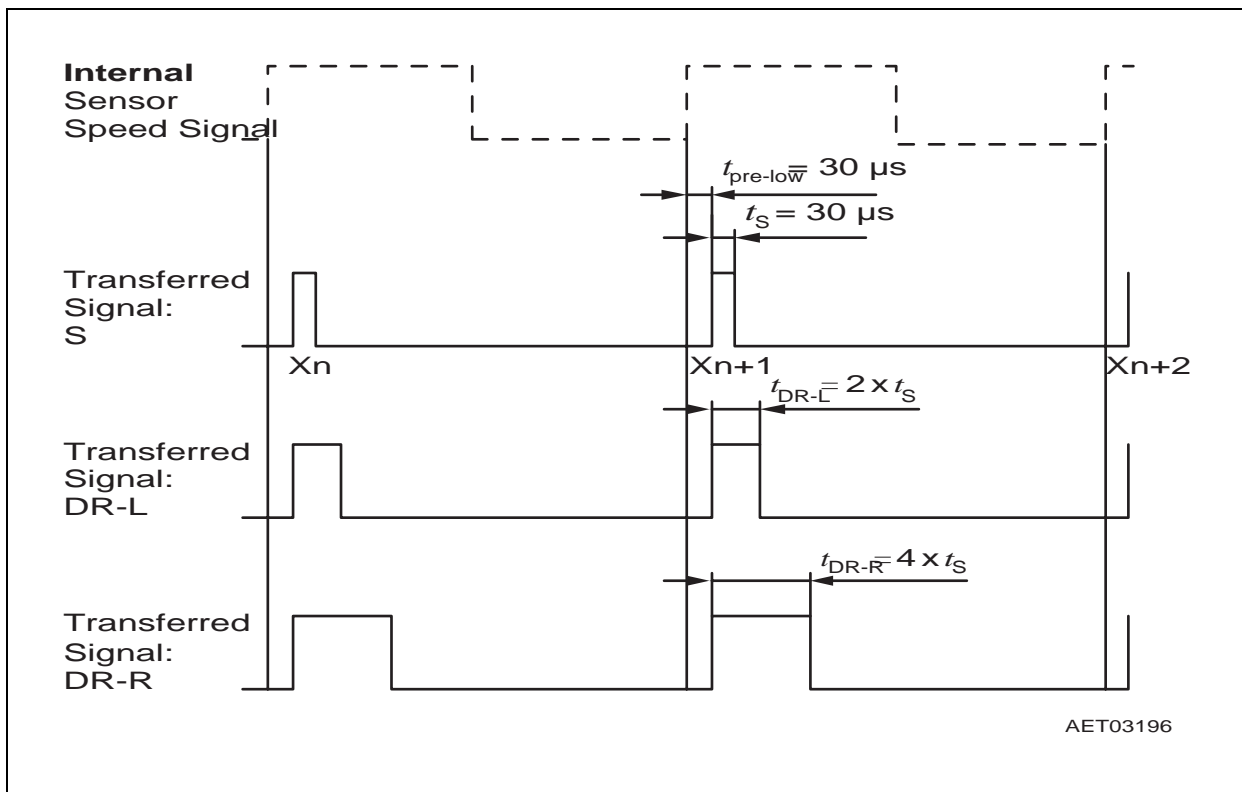


If the magnetic direction field exceeds  $\Delta B_{Dir}$ , the output pulse lengths are 60  $\mu s$  or 120  $\mu s$  respectively, depending on the direction of rotation.

If the magnitude of the magnetic direction field is below  $\Delta B_{dir}$ , the output pulses are suppressed when the frequency is below  $f_{DR,max}$  (see section vibration suppression). For magnitudes of the magnetic differential field below  $\Delta B_{Limit}$  the signal is lost.

Speed pulse occur only at the first pulse after start up or above  $f_{DR,max}$ .

If no magnetic differential signal change is detected the IC will remain in calibrated mode. No internal reset are generated - therefore a zero speed operation is possible.



**Figure 6 Definition of PWM Current Interface**

**Electro Magnetic Compatibility** (values depend on  $R_M$ !)

Characterization of Electro Magnetic Compatibility are carried out on sample base of one qualification lot. Not all specification parameters have been monitored during EMC exposure. Only key parameters as e.g. switching current have been monitored

Parameter	Symbol	Level/Typ	Status
Ref. ISO 7637-1; test circuit 1; $\Delta B = 2 \text{ mT}$ (amplitude of sinus signal); $V_{CC} = 13.5 \text{ V}$ , $f_B = 100 \text{ Hz}$ ; $T = 25 \text{ }^\circ\text{C}$ ; $R_M \geq 75 \Omega$			
Testpulse 1	$V_{EMC}$	IV / – 100 V	C <sup>1)</sup>
Testpulse 2		IV / 100 V	C <sup>1)</sup>
Testpulse 3a		IV / – 150 V	A
Testpulse 3b		IV / 100 V	A
Testpulse 4		IV / – 7 V	B <sup>2)</sup>
Testpulse 5		IV / 86.5 <sup>3)</sup> V	C

1) According to 7637-1 the supply switched "OFF" for  $t = 200 \text{ ms}$ .

2) According to 7637-1 for test pulse 4 the test voltage shall be  $12 \text{ V} \pm 0.2 \text{ V}$ . Measured with  $R_M = 75 \Omega$  only.

Mainly the current consumption will decrease. Status C with test circuit 1.

3) Applying in the board net a suppressor diode with sufficient energy absorption capability.

**Ref. ISO 7637-3; test circuit 1;**

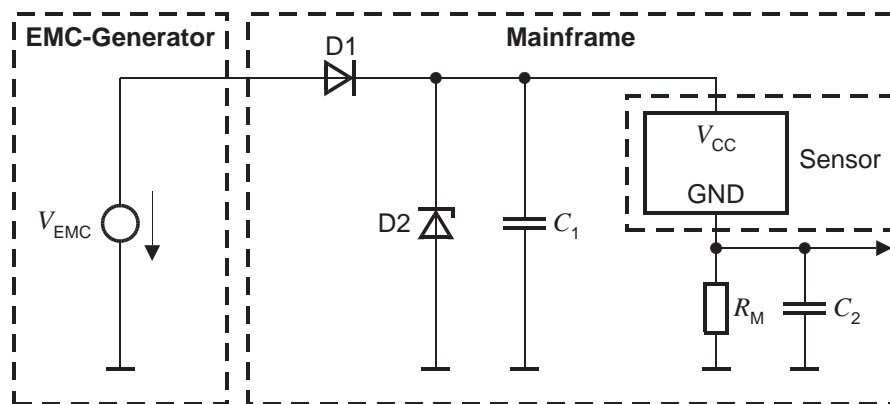
$\Delta B = 2 \text{ mT}$  (amplitude of sinus signal);  $V_{CC} = 13.5 \text{ V}$ ,  $f_B = 100 \text{ Hz}$ ;  $T = 25 \text{ }^\circ\text{C}$ ;  $R_M \geq 75 \Omega$

Testpulse 1	$V_{EMC}$	IV / – 30 V	A
Testpulse 2		IV / 30 V	A
Testpulse 3a		IV / – 60 V	A
Testpulse 3b		IV / 40 V	A

**Ref. ISO 11452-3; test circuit 1; measured in TEM-cell**

$\Delta B = 2 \text{ mT}$ ;  $V_{CC} = 13.5 \text{ V}$ ,  $f_B = 100 \text{ Hz}$ ;  $T = 25 \text{ }^\circ\text{C}$

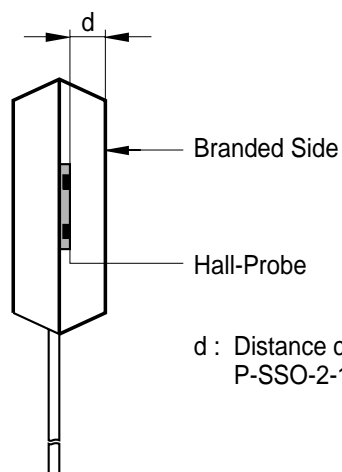
EMC field strength (TLE4953)	$E_{\text{TEM-Cell}}$	IV / 200 V/m	AM = 80%, $f = 1 \text{ kHz}$
EMC field strength (TLE4953C)	$E_{\text{TEM-Cell}}$	IV / 250 V/m	AM = 80%, $f = 1 \text{ kHz}$



AES03199

Components: D1: 1N4007  
D2: T 5Z27 1J  
 $C_1$ : 10  $\mu$ F/35 V  
 $C_2$ : 1 nF/1000 V  
 $R_M$ : 75  $\Omega$ /5 W

**Figure 7 Test Circuit 1**



$d$  : Distance chip to branded side of IC  
P-SSO-2-1/2 :  $0.3 \pm 0.08$  mm

AEA02961

**Figure 8 Package Outlines**

Technical drawing of a 10-pitch tape, showing dimensions and tolerances. The drawing includes a side view and a cross-sectional view.

**Side View Dimensions:**

- Top edge dimensions:  $5.34 \pm 0.05$ ,  $5.16 \pm 0.08$ ,  $12.7 \pm 1$ ,  $0.1 \text{ MAX.}$ ,  $1.2 \pm 0.1$ ,  $23.8 \pm 0.5$ ,  $38 \text{ MAX.}$
- Bottom edge dimensions:  $6.35 \pm 0.4$ ,  $12.7 \pm 0.3$ ,  $4 \pm 0.3$
- Internal features:  $1.9 \text{ MAX.}$ ,  $1 \times 45^\circ \pm 1^\circ$ ,  $0.87 \pm 0.05$ ,  $1.67 \pm 0.05$ ,  $0.5$ ,  $2x$ ,  $1$ ,  $2$ ,  $2.54$ ,  $9^{+0.75}_{-0.5}$
- Surface texture:  $Ra = 0.2$ ,  $Ra = 0.1$
- Other:  $1 \text{ MAX.}$ ,  $(0.25)$ ,  $(14.8)$ ,  $(\text{Useable Length})$

**Cross-sectional View Dimensions:**

- Top edge dimensions:  $1^{-0.1}$ ,  $0.25 \pm 0.05$ ,  $0.2^{+0.1}$ ,  $1^{-1}$ ,  $6 \pm 0.5$ ,  $0.25^{-0.15}$ ,  $0.39 \pm 0.1$
- Internal features:  $7^\circ$ ,  $7^\circ$ ,  $18 \pm 0.5$
- Labels: **Adhesive Tape**, **Tape**, **A**

**Notes:**

- Total tolerance at 10 pitches  $\pm 1$

Dimensions in mm

[illegible]

1) No solder function area

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## Данный компонент на территории Российской Федерации

**Вы можете приобрести в компании MosChip.**

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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